

Vishay Semiconductors

USB-OTG BUS-Port ESD-Protection for V_{BUS} = 28 V

COMPLIANT

GREEN (5-2008)**

Features

- Ultra compact LLP75-7L package
- Low package height < 0.6 mm
- 3-line USB ESD-protection with max. working range = 5.5 V
- VBUS-protection with 28 V working range RoHS
- Low leakage current
- Low load capacitance C_D = 0.7 pF
- ESD-protection to IEC 61000-4-2 ± 8 kV contact discharge
 - ± 15 kV air discharge
- Surge current acc. IEC 61000-4-5 I_{PP} > 3 A
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Marking (example only)

Ordering Information



Dot = Pin 1 marking XX = Date code YY = Type code (see table below)

Device name	Ordering code	Taped units per reel (8 mm tape on 7" reel)	Minimum order quantity		
VBUS053CZ-HAF	VBUS053CZ-HAF-G-08	15 000	15 000		

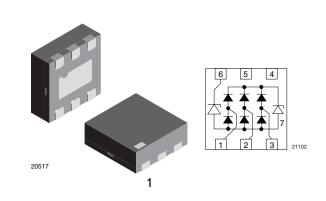
Package Data

Device name	Package name	Marking code	Weight	Molding compound flammability rating	Moisture sensitivity level	Soldering conditions	
VBUS053CZ-HAF	LLP75-7L	UA	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	

Absolute Maximum Ratings

Parameter	Test conditions	Symbol	Value	Unit				
Data line D+, D-, ID: Pin 1, 2 and 3 to ground (pin 7)								
Peak pulse current	Acc. IEC 61000-4-5; $t_p = 8/20 \mu s/single shot$	I _{PPM}	3	А				
Peak pulse power	Acc. IEC 61000-4-5; $t_p = 8/20 \mu s/single shot$	P _{PP}	36	W				
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV				
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV				
V _{BUS} : Pin 6 to ground (pin 7)								
Peak pulse current	Acc. IEC 61000-4-5; t _p = 8/20 μs/single shot	I _{PPM}	3	А				
Peak pulse power	Acc. IEC 61000-4-5; t _p = 8/20 μs/single shot	P _{PP}	180	W				
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 8	kV				
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV				
Operating temperature	Junction temperature	TJ	- 40 to + 125					
Storage temperature		T _{STG}	- 55 to + 150	°C				

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902



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Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified

VBUS053CZ-HAF

All inputs (pin 1, 2, and 3) to ground (pin 7)

Parameter	Test conditions/remarks	Symbol	Min.	Тур.	Max.	Unit
Protection paths	Number of line which can be protected	N lines			3	lines
Reverse working voltage	at I _R = 0.1 μA	V _{RWM}	5.5			V
Reverse current	at $V_R = V_{RWM} = 3.3 \text{ V}; \text{ T} = 65 ^\circ\text{C}$	I _R			0.085	μA
neverse current	at $V_{R} = V_{RWM} = 5.5 V$	I _R			1	μA
Forward voltage	at I _F = 15 mA	V _F	0.7		1.2	V
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6.5		10	V
Reverse clamping voltage	at I _{PP} = 1 A; acc. IEC 61000-4-5	V _C		10	12	V
	at I _{PP} = 3 A; acc. IEC 61000-4-5	V _C		15	18	V
Forward clamping voltage	at I _F = 3 A; acc. IEC 61000-4-5	V _F		3.4	4.1	V
Line capacitance	Test pin at V _R = 0 V; any other I/O pin at V _R = 3.3 V, f = 1 MHz	CD		0.7	1	pF
Line symmetry	Difference of the line capacitance	dC _D			0.1	pF
Line to line capacitance	Among pins 1, 2 and 3 at V _R = 0 V; f = 1 MHz	C _{DD}		0.35	0.5	pF

$V_{BUS}\xspace$ (pin 6) to ground (pin 7)

Parameter	Test conditions/remarks	Symbol	Min.	Тур.	Max.	Unit
Protection paths	Number of line which can be protected	N lines			1	line
Reverse working voltage	at I _R = 100 nA	V _{RWM}	28			V
Reverse current	at $V_R = V_{RWM} = 28 V$	I _R			100	nA
Forward voltage	at I _F = 10 mA	V _F	0.6	0.75	0.9	V
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	32		40	V
Reverse clamping voltage	at I _{PP} = 1 A; acc. IEC 61000-4-5; T = 25 $^{\circ}\text{C}$	V _C		41	48	V
	at I _{PP} = 3 A; acc. IEC 61000-4-5; T = 25 °C	V _C		53	60	V
Forward clamping voltage	at I _F = 3 A; acc. IEC 61000-4-5	V _F			2.2	V
Line capacitance	at V _R = 0 V; f = 1 MHz	CD		40	50	pF



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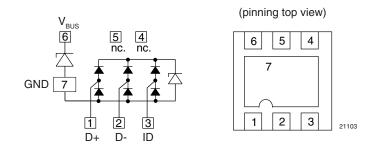
Application Note

The VBUS053CZ-HAF is intended as an ESD-protection and transient voltage suppressor for one USB-OTG port.

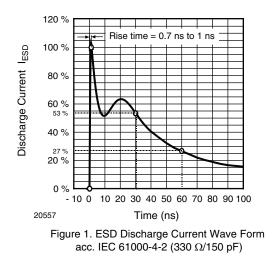
The LLP75-7L package contains two separate dies which are mounted on a common ground plane (pin 7). The high-speed data lines D+, D- and ID, are connected to pins 1, 2, and 3. As long as the signal voltage on the data lines is between the ground- and the 5 V working range, the low capacitance PN-diodes offer a very high isolation to ground and to the other data lines. But as soon as any transient signal like an ESD-signal, exceeds this working range of 5 V in either the positive or negative direction, one of the PN-diodes gets into the forward mode and clamps the transient either to ground or to the avalanche break through level.

An extra avalanche diode (separate die) clamps the supply line voltage (V_{BUS} at pin 6) above the 28 V working range to ground (pin 7).

Due to the "two die construction" the V_{BUS} line has a very high isolation to the data lines. In case of a destructive transient signal, i.e. coming from a charger, the data lines will not be influenced.



Typical Characteristics (T_{amb} = 25 °C, unless otherwise specified)



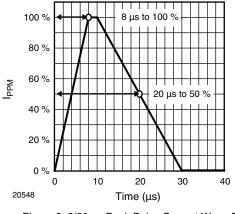
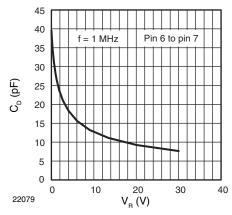
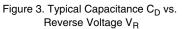


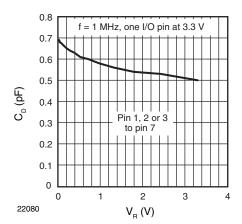
Figure 2. 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

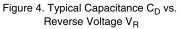
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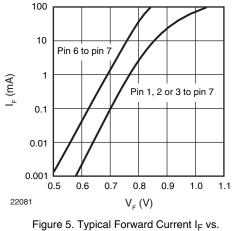


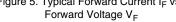












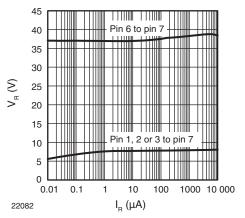


Figure 6. Typical Reverse Voltage V_R vs. Reverse Current I_R

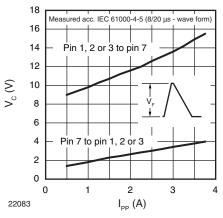


Figure 7. Typical Peak Clamping Voltage V_{C} vs. Peak Pulse Current I_{PP}

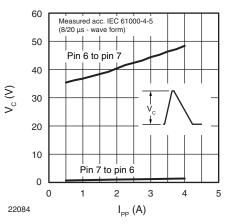
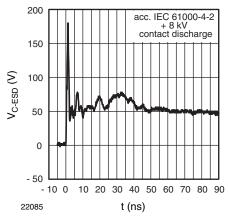
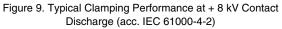


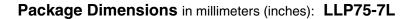
Figure 8. Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}

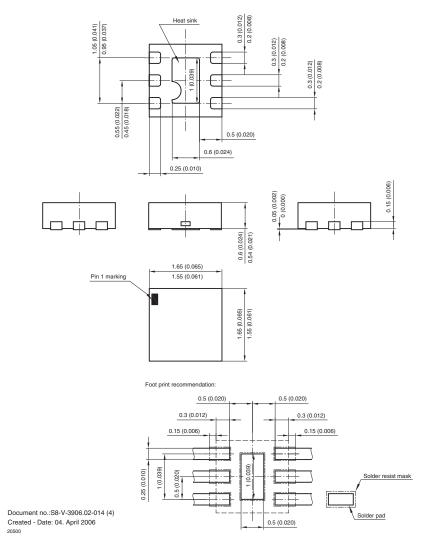


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